PTO/SB/08A (10-01)
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U. S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet 1 of 4

Complete if Known	
Application Number	09/988,984
Filing Date	November 19, 2001
First Named Inventor	John T. Moore
Art Unit	~~2812~~ 2823
Examiner Name	~~Not Yet Assigned~~ T. PHAM
Attorney Docket Number	M4065.0608/P608

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No.[1]	Document Number: Number-Kind Code[2] (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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	BB					

Examiner Signature		Date Considered	7/21/03

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Attorney Docket Number	M4065.0608/P608

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS

Examiner Initials	Cite No.[1]	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T[2]
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	CQ		

Examiner Signature		Date Considered	7/21/03

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